

IN THE SPECIFICATION:

Please amend the specification at page 1, the section titled "Related Applications," lines 7-20:

The present application is related to commonly assigned and copending U.S. Patent Application 09/894,479 (Attorney Docket No. 00-113-TAP) entitled "REDUCED SENSITIVITY SPIN VALVE HEAD FOR MAGNETIC TAPE APPLICATIONS," U.S. Patent Application 09/894,379 (Attorney Docket No. 2001-019-TAP) entitled "APPARATUS AND METHOD OF MAKING A REDUCED SENSITIVITY SPIN VALVE SENSOR APPARATUS IN WHICH A BASIC MAGNETIC SENSITIVITY IS REDUCED," and U.S. Patent Application 09/986,162 (Attorney Docket No. 2001-020-TAP) entitled "APPARATUS AND METHOD OF MAKING A REDUCED SENSITIVITY SPIN VALVE SENSOR APPARATUS IN WHICH A FLUX CARRYING CAPACITY IS INCREASED," all of which are filed on even date herewith and are hereby incorporated by reference.

Please amend the specification at page 19, lines 13-30:

The use of an antiferromagnetic layer in a magneto-resistive element is generally taught in commonly assigned and copending U.S. Patent Application Serial No. 09/894,479 (Attorney Docket No. 98-013-TAP) entitled "Dual Element Magnetoresistive Read Head with Integral Element Stabilization," filed on _____, and which is hereby incorporated by reference. In this application, an antiferromagnetic layer is used in a normal magnetoresistive read head for stabilizing a magnetic domain of the magnetoresistive read head. An undesirable consequence of using the antiferromagnetic layer in this application was the loss of sensitivity of the MR layer. The present invention recognizes the value of loss of sensitivity in this manner when applied to spin valve sensors for magnetic tape read heads, an advantage not recognized in this prior incorporated U.S. Patent Application Serial No. 09/894,479 (Attorney Docket No. 98-013-TAP).